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CONFIRMATION NO. 3879

<b>SERIAL NUMBER</b> 10/694,030	<b>FILING OR 371(c) DATE</b> 10/28/2003 <b>RULE</b>	<b>CLASS</b> 257	<b>GROUP ART UNIT</b> 2815	<b>ATTORNEY DOCKET NO.</b> 1514.1033	
<b>APPLICANTS</b> Ji Yong Park, Suwon-city, KOREA, REPUBLIC OF; Hye Hyang Park, Suwon-city, KOREA, REPUBLIC OF; <b>** CONTINUING DATA *****</b> <i>None m</i> <b>** FOREIGN APPLICATIONS *****</b> <i>Yes m</i> REPUBLIC OF KOREA 2003-13829 03/05/2003 <b>IF REQUIRED, FOREIGN FILING LICENSE GRANTED</b> <b>** 01/24/2004</b>					
Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after met Verified and <i>Allowance</i> Acknowledged <i>Examiner's Signature</i> Initials		<b>STATE OR COUNTRY</b> KOREA, REPUBLIC OF	<b>SHEETS DRAWING</b> 9	<b>TOTAL CLAIMS</b> 23	<b>INDEPENDENT CLAIMS</b> 5
<b>ADDRESS</b> 49455					
<b>TITLE</b> Polycrystalline silicon thin film, fabrication method thereof, and thin film transistor without directional dependency on active channels fabricated using the same					
<b>FILING FEE RECEIVED</b> 1496	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit		